

RD74LVC1G125

Bus Buffer with 3-state Output

REJ03D0731-0100

Rev.1.00

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Description

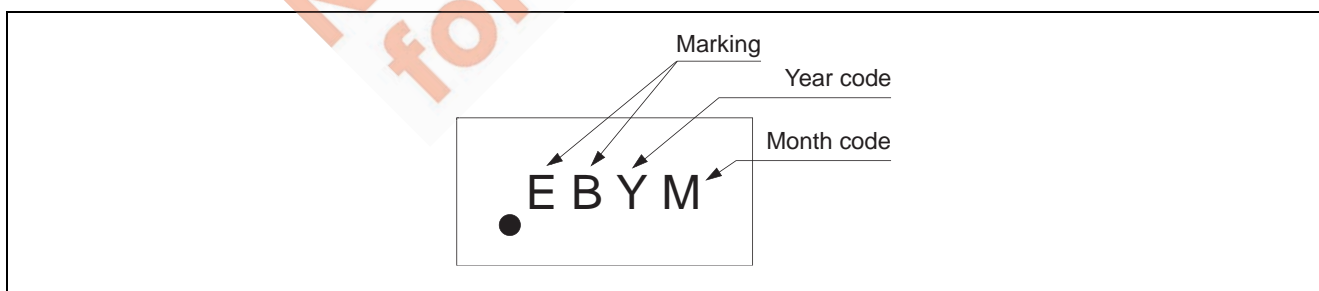
The RD74LVC1G125 has bus buffer with 3-state output in a 5-pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as renesas uni logic series.
- Supply voltage range: 1.65 to 5.5 V
- Operating temperature range: -40 to +85°C
- All inputs: $V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V \text{ to } 5.5 V)$
- All outputs: $V_O (Max.) = 5.5 V (@V_{CC} = 0 V)$
- Output current:
 - $\pm 4 \text{ mA } (@V_{CC} = 1.65 V)$
 - $\pm 8 \text{ mA } (@V_{CC} = 2.3 V)$
 - $\pm 24 \text{ mA } (@V_{CC} = 3.0 V)$
 - $\pm 32 \text{ mA } (@V_{CC} = 4.5 V)$
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC1G125WPE	WCSP-5 pin	SXBG0005LB-A (TBS-5CV)	WP	E (3,000 pcs/reel)

Article Indication

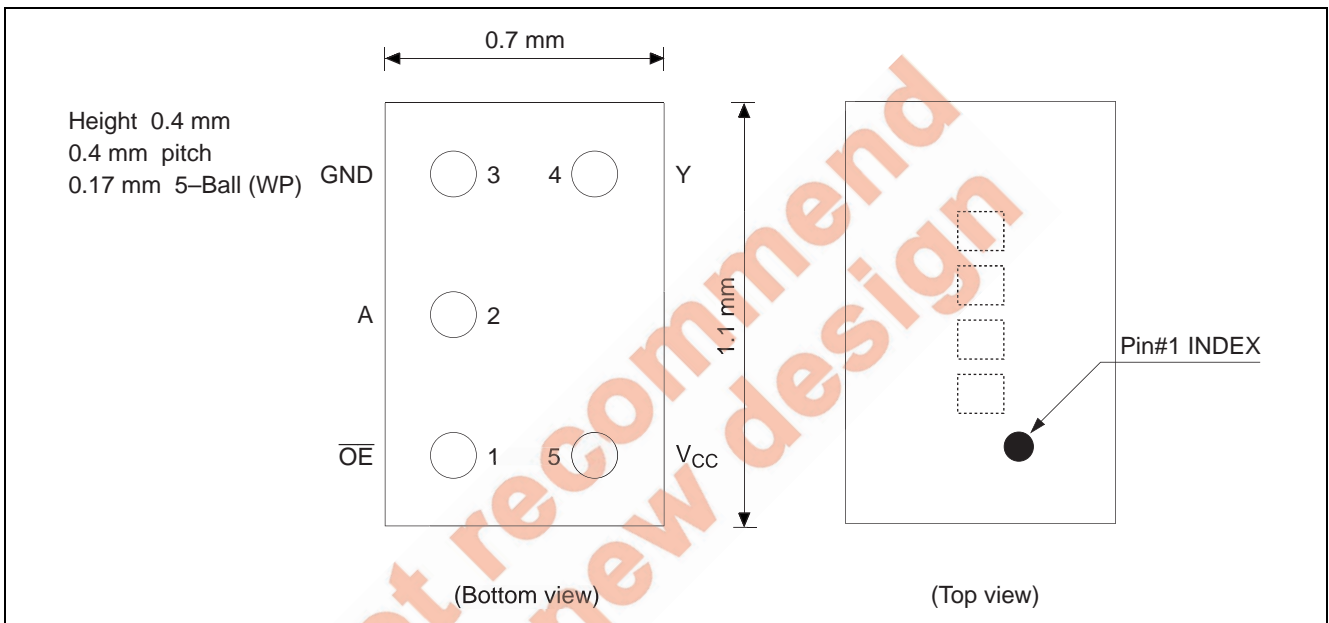


Function Table

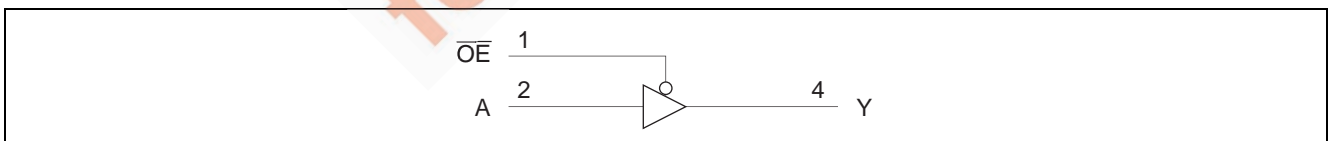
Inputs		Output Y
\overline{OE}	A	
L	H	H
L	L	L
H	X	Z

H: High level
 L: Low level
 X: Immaterial
 Z: High impedance

Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V_{CC}	-0.5 to 6.5	V	
Input voltage range ^{*1}	V_I	-0.5 to 6.5	V	
Output voltage range ^{*1, 2}	V_O	-0.5 to $V_{CC} + 0.5$	V	Output : H or L
		-0.5 to 6.5		V_{CC} : OFF or Output "Z"
Input clamp current	I_{IK}	-50	mA	$V_I < 0$
Output clamp current	I_{OK}	-50	mA	$V_O < 0$
Continuous output current	I_O	± 50	mA	$V_O = 0$ to V_{CC}
Continuous current through V_{CC} or GND	I_{CC} or I_{GND}	± 100	mA	
Package Thermal impedance	θ_{ja}	200	$^{\circ}C/W$	WP
Storage temperature	T_{stg}	-65 to 150	$^{\circ}C$	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- This value is limited to 5.5 V maximum.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	1.65	5.5	V	
Input voltage range	V_I	0	5.5	V	
Output voltage range	V_O	0	V_{CC}	V	
		0	5.5		Output : Z
Output current	I_{OL}	—	4	mA	$V_{CC} = 1.65$ V
		—	8		$V_{CC} = 2.3$ V
		—	16		$V_{CC} = 3.0$ V
		—	24		
		—	32		$V_{CC} = 4.5$ V
	I_{OH}	—	-4		$V_{CC} = 1.65$ V
		—	-8		$V_{CC} = 2.3$ V
		—	-16		$V_{CC} = 3.0$ V
		—	-24		
		—	-32		$V_{CC} = 4.5$ V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	20	ns / V	$V_{CC} = 1.65$ to 1.95 V, 2.3 to 2.7 V
		0	10		$V_{CC} = 3.0$ to 3.6 V
		0	5		$V_{CC} = 4.5$ to 5.5 V
Operating free-air temperature	T_a	-40	85	$^{\circ}C$	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Ta = -40 to 85°C

Item	Symbol	V _{CC} (V)	Min	Typ	Max	Unit	Test condition			
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	—	—	V				
		2.3 to 2.7	1.7	—	—					
		3.0 to 3.6	2.0	—	—					
		4.5 to 5.5	V _{CC} ×0.7	—	—					
	V _{IL}	1.65 to 1.95	—	—	V _{CC} ×0.35					
		2.3 to 2.7	—	—	0.7					
		3.0 to 3.6	—	—	0.8					
		4.5 to 5.5	—	—	V _{CC} ×0.3					
Output voltage	V _{OH}	Min to Max	V _{CC} -0.1	—	—	V	I _{OH} = -100 μA			
		1.65	1.2	—	—		I _{OH} = -4 mA			
		2.3	1.9	—	—		I _{OH} = -8 mA			
		3.0	2.4	—	—		I _{OH} = -16 mA			
			2.3	—	—		I _{OH} = -24 mA			
		4.5	3.8	—	—		I _{OH} = -32 mA			
	V _{OL}	Min to Max	—	—	0.1		I _{OL} = 100 μA			
		1.65	—	—	0.45		I _{OL} = 4 mA			
		2.3	—	—	0.3		I _{OL} = 8 mA			
		3.0	—	—	0.4		I _{OL} = 16 mA			
			—	—	0.55		I _{OL} = 24 mA			
		4.5	—	—	0.55		I _{OL} = 32 mA			
		Input current	I _{IN}	0 to 5.5	—		—	±5	μA	V _{IN} = 5.5 V or GND
		Off state Output current	I _{OZ}	3.6	—		—	10	μA	V _O = 5.5 V or GND
Quiescent supply current	I _{CC}	1.65 to 5.5	—	—	10	μA	V _{IN} = V _{CC} or GND, I _O = 0			
	ΔI _{CC}	3 to 5.5	—	—	500		One input at V _{CC} -0.6 V, Other input at V _{CC} or GND			
Output leakage current	I _{OFF}	0	—	—	±10	μA	V _{IN} or V _O = 0 to 5.5 V			
Input capacitance	C _{IN}	3.3	—	3.5	—	pF	V _{IN} = V _{CC} or GND			

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$

Item	Symbol	Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Max				
Propagation delay time	t _{PLH}	2.8	8.0	ns	C _L = 30 pF, R _L = 1.0 kΩ	A	Y
	t _{PHL}						
Output enable time	t _{ZH} t _{ZL}	3.3	9.4	ns			
Output disable time	t _{HZ} t _{LZ}	1.3	9.2	ns		$\overline{\text{OE}}$	Y

 $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Item	Symbol	Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Max				
Propagation delay time	t _{PLH}	1.2	5.5	ns	C _L = 30 pF, R _L = 500 Ω	A	Y
	t _{PHL}						
Output enable time	t _{ZH} t _{ZL}	1.5	6.6	ns			
Output disable time	t _{HZ} t _{LZ}	1.0	5.0	ns		$\overline{\text{OE}}$	Y

 $V_{CC} = 3.3 \pm 0.3 \text{ V}$

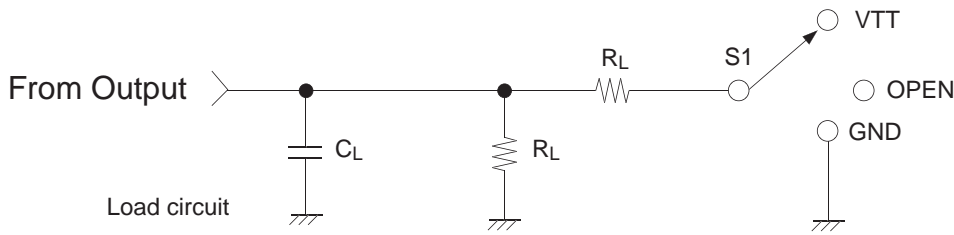
Item	Symbol	Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Max				
Propagation delay time	t _{PLH}	1.0	4.5	ns	C _L = 50 pF, R _L = 500 Ω	A	Y
	t _{PHL}						
Output enable time	t _{ZH} t _{ZL}	1.0	5.3	ns			
Output disable time	t _{HZ} t _{LZ}	1.0	5.0	ns		$\overline{\text{OE}}$	Y

 $V_{CC} = 5.0 \pm 0.5 \text{ V}$

Item	Symbol	Ta = -40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Max				
Propagation delay time	t _{PLH}	1.0	4.0	ns	C _L = 50 pF, R _L = 500 Ω	A	Y
	t _{PHL}						
Output enable time	t _{ZH} t _{ZL}	1.0	5.0	ns			
Output disable time	t _{HZ} t _{LZ}	1.0	4.2	ns		$\overline{\text{OE}}$	Y

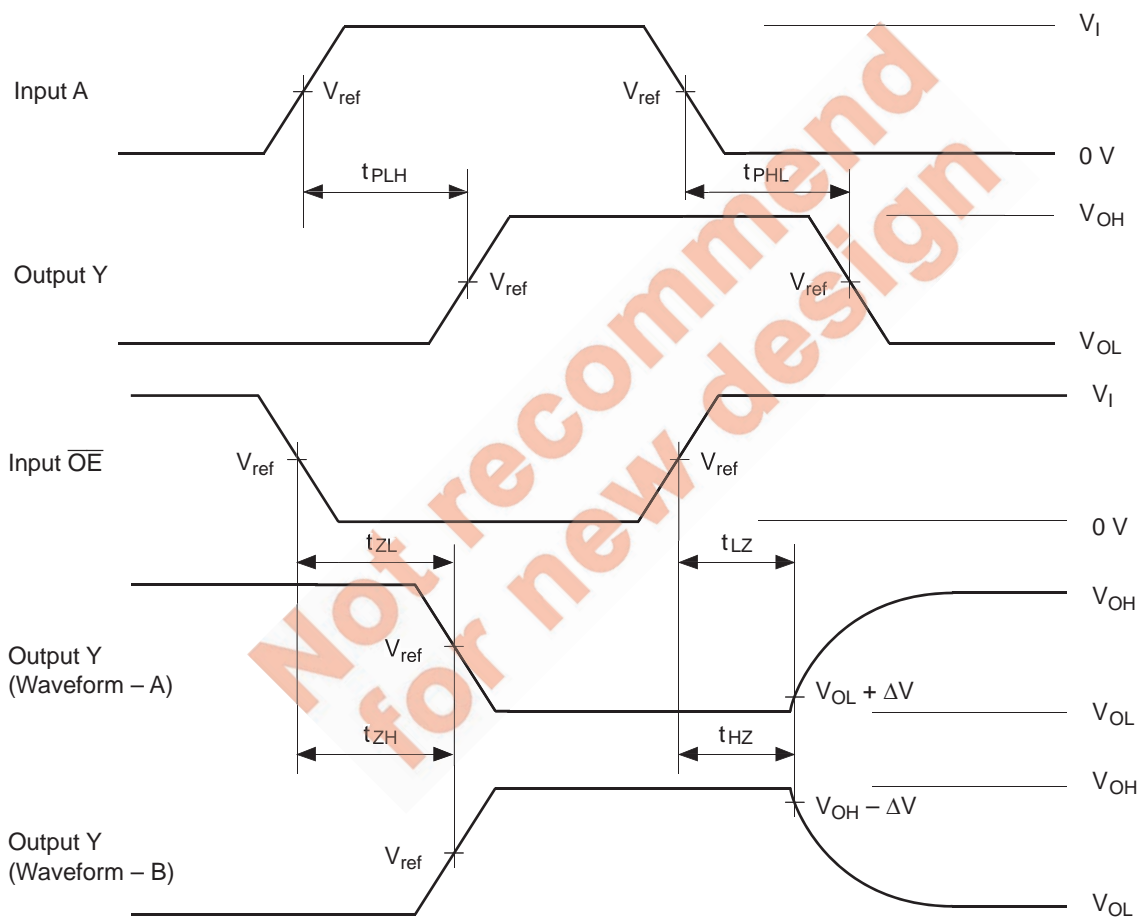
Operating Characteristics

Item	Symbol	V _{CC} (V)	Ta = 25°C			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C _{PD}	1.8	—	19	—	pF	f = 10 MHz
		2.5	—	19	—		
		3.3	—	20	—		
		5.0	—	22	—		



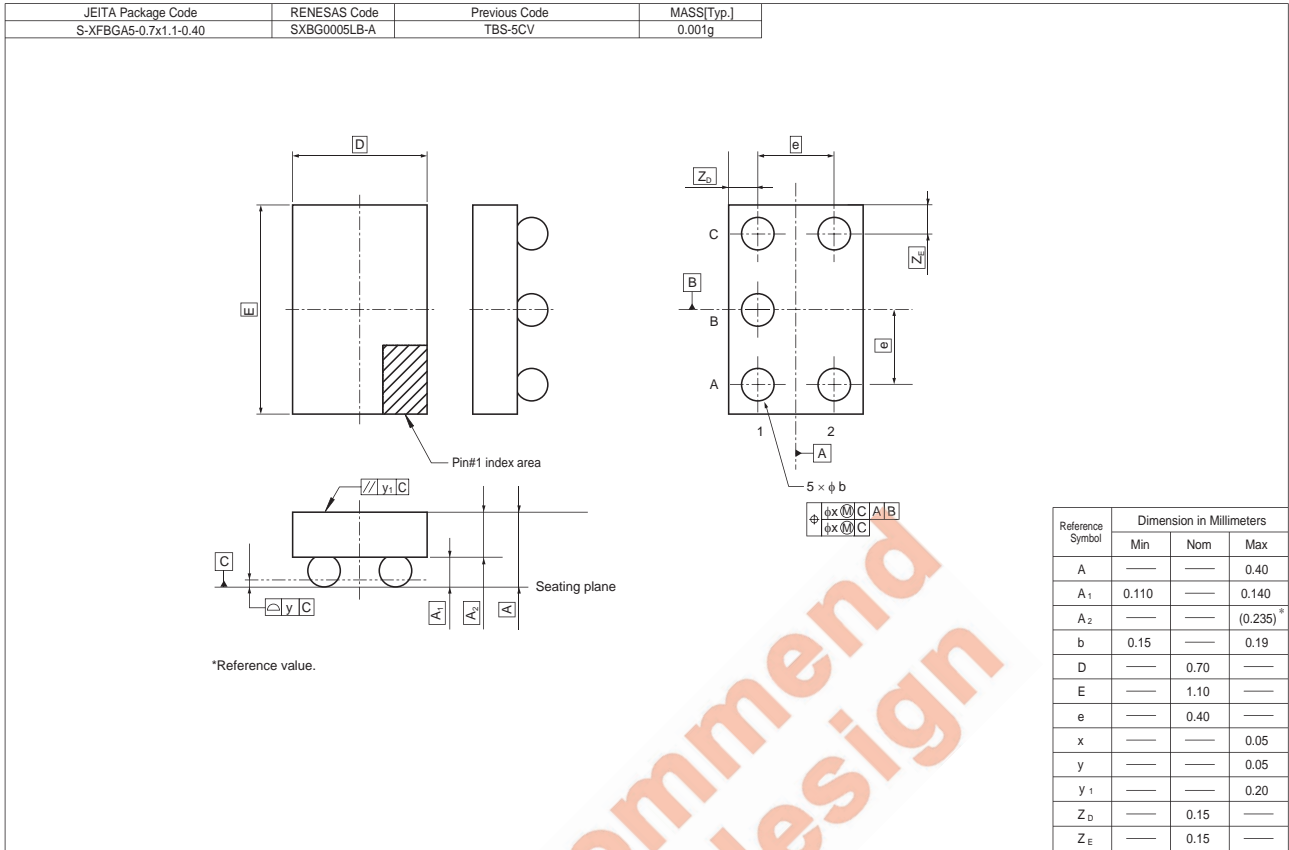
TEST	S1
t_{PLH} / t_{PHL}	OPEN
t_{ZH} / t_{HZ}	GND
t_{ZL} / t_{LZ}	VTT

V_{CC} (V)	INPUTS		V_{ref}	VTT	C_L	R_L	ΔV
	V_I	t_r / t_f					
1.8 ± 0.15	V_{CC}	≤ 2 ns	$V_{CC} / 2$	$2 \times V_{CC}$	30 pF	1.0 k Ω	0.15 V
2.5 ± 0.2	V_{CC}	≤ 2 ns	$V_{CC} / 2$	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
3.3 ± 0.3	V_{CC}	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5.0 ± 0.5	V_{CC}	≤ 2.5 ns	$V_{CC} / 2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



- Notes:
- C_L includes probe and jig capacitance.
 - Waveform-A is for an output with internal conditions such that the output is low except when disabled by the output control.
 - Waveform-B is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics:
PRR \leq 10MHz, $Z_o = 50 \Omega$.
 - The output are measured one at a time with one transition per measurement.

Package Dimensions



Not recommended for new design

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